



# PJE8405

## 30V P-Channel Enhancement Mode MOSFET – ESD Protected

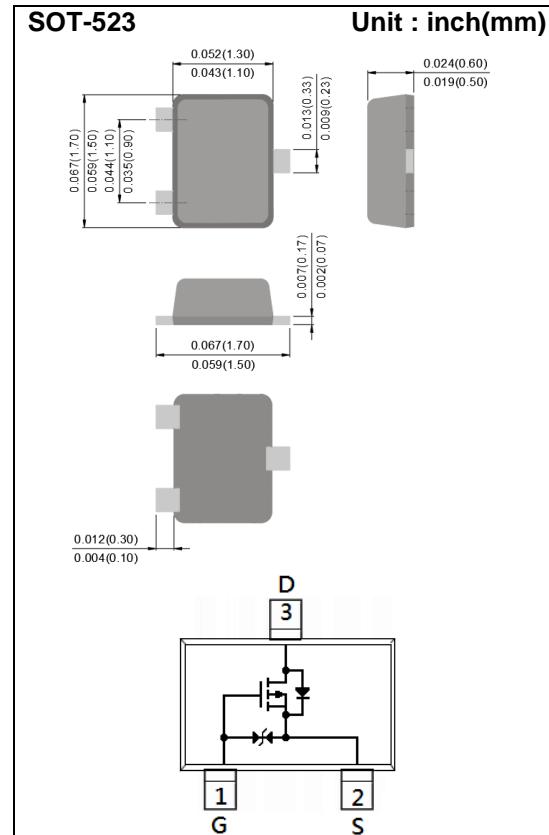
**Voltage** **-30 V**    **Current** **-0.5A**

### Features

- RDS(ON) , VGS@-4.5V, ID@-0.5A<390mΩ
- RDS(ON) , VGS@-2.5V, ID@-0.3A<560mΩ
- RDS(ON) , VGS@-1.8V, ID@-0.1A<990mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-523 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.002 grams
- Marking : E05



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL          | LIMIT   | UNITS                     |
|---|-----------------|---------|---------------------------|
| Drain-Source Voltage  | $V_{DS}$        | -30     | V                         |
| Gate-Source Voltage   | $V_{GS}$        | $\pm 8$ | V                         |
| Continuous Drain Current  | $I_D$           | -0.5    | A                         |
| Pulsed Drain Current  | $I_{DM}$        | -2.0    | A                         |
| Power Dissipation<br><br>T <sub>a</sub> =25°C                           | $P_D$           | 300     | mW                        |
|   |                 | 2.4     | mW/ $^\circ\text{C}$      |
| Operating Junction and Storage Temperature Range                        | $T_J, T_{STG}$  | -55~150 | $^\circ\text{C}$          |
| Typical Thermal Resistance<br>- Junction to Ambient <sup>(Note 3)</sup> | $R_{\theta JA}$ | 417     | $^\circ\text{C}/\text{W}$ |



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL                     | TEST CONDITION   | MIN. | TYP.      | MAX.     | UNITS            |
|---|----------------------------|--|------|-----------|----------|------------------|
| <b>Static</b>   |                            |  |      |           |          |                  |
| Drain-Source Breakdown Voltage                        | $\text{BV}_{\text{DSS}}$   | $V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$  | -30  | -         | -        | V                |
| Gate Threshold Voltage                                | $V_{\text{GS}(\text{th})}$ | $V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$  | -0.5 | -0.98     | -1.3     | V                |
| Drain-Source On-State Resistance                      | $R_{\text{DS}(\text{on})}$ | $V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-0.5\text{A}$  | -    | 318       | 390      | $\text{m}\Omega$ |
|   |                            | $V_{\text{GS}}=-2.5\text{V}, I_{\text{D}}=-0.3\text{A}$  | -    | 427       | 560      |                  |
|   |                            | $V_{\text{GS}}=-1.8\text{V}, I_{\text{D}}=-0.1\text{A}$  | -    | 853       | 990      |                  |
| Zero Gate Voltage Drain Current                       | $I_{\text{DSS}}$           | $V_{\text{DS}}=-30\text{V}, V_{\text{GS}}=0\text{V}$   | -    | -0.01     | -1       | $\mu\text{A}$    |
| Gate-Source Leakage Current                           | $I_{\text{GSS}}$           | $V_{\text{GS}}=\pm 8\text{V}, V_{\text{DS}}=0\text{V}$   | -    | $\pm 3.2$ | $\pm 10$ | $\mu\text{A}$    |
| <b>Dynamic</b>  |                            |  |      |           |          |                  |
| Total Gate Charge                                     | $Q_g$                      | $V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-0.5\text{A}, V_{\text{GS}}=-4.5\text{V}^{\text{(Note 1,2)}}$                       | -    | 1.6       | -        | $\text{nC}$      |
| Gate-Source Charge                                    | $Q_{\text{gs}}$            |  | -    | 0.5       | -        |                  |
| Gate-Drain Charge                                     | $Q_{\text{gd}}$            |  | -    | 0.3       | -        |                  |
| Input Capacitance                                     | $C_{\text{iss}}$           | $V_{\text{DS}}=-15\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHZ}$  | -    | 137       | -        | $\text{pF}$      |
| Output Capacitance                                    | $C_{\text{oss}}$           |  | -    | 23        | -        |                  |
| Reverse Transfer Capacitance                          | $C_{\text{rss}}$           |  | -    | 10        | -        |                  |
| <b>Switching</b>                                      |                            |  |      |           |          |                  |
| Turn-On Delay Time                                    | $t_{\text{d}(\text{on})}$  | $V_{\text{DD}}=-15\text{V}, I_{\text{D}}=-0.5\text{A}, V_{\text{GS}}=-4.5\text{V}, R_{\text{G}}=6\Omega^{\text{(Note 1,2)}}$ | -    | 11        | -        | $\text{ns}$      |
| Turn-On Rise Time                                     | $t_{\text{r}}$             |  | -    | 52        | -        |                  |
| Turn-Off Delay Time                                   | $t_{\text{d}(\text{off})}$ |  | -    | 65        | -        |                  |
| Turn-Off Fall Time                                    | $t_{\text{f}}$             |  | -    | 46        | -        |                  |
| <b>Drain-Source Diode</b>                             |                            |  |      |           |          |                  |
| Maximum Continuous Drain-Source Diode Forward Current | $I_s$                      | ---  | -    | -         | -0.4     | A                |
| Diode Forward Voltage                                 | $V_{\text{SD}}$            | $I_s=-1.0\text{A}, V_{\text{GS}}=0\text{V}$  | -    | -0.93     | -1.2     | V                |

### NOTES :

1. Pulse width $\leq 300\mu\text{s}$ , Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\text{OJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

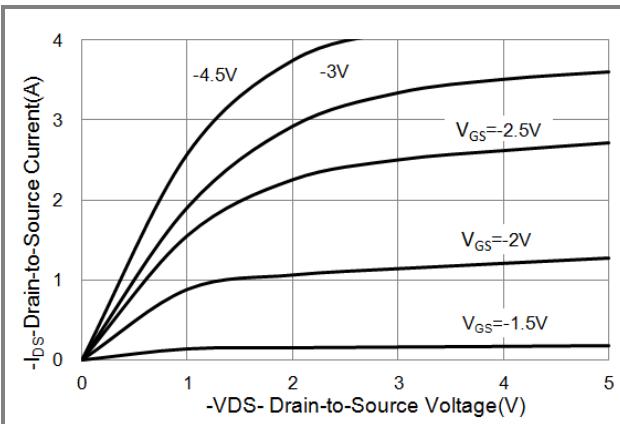


Fig.1 On-Region Characteristics

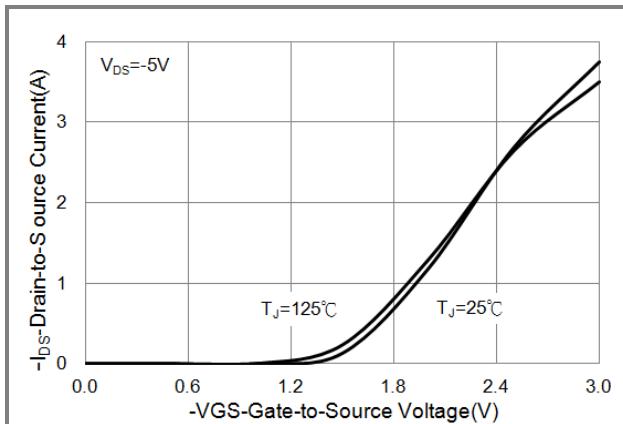


Fig.2 Transfer Characteristics

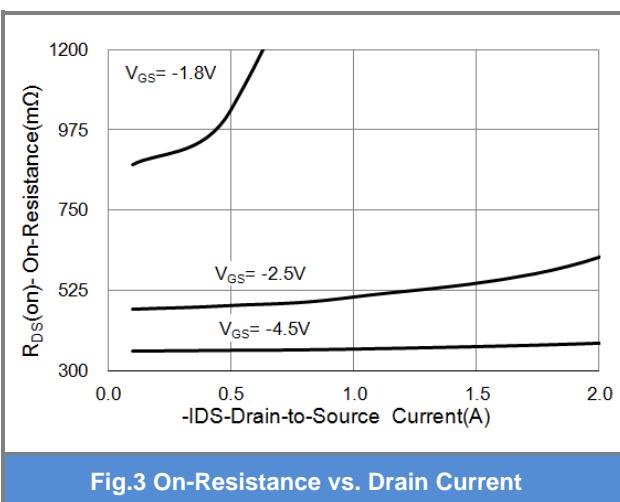


Fig.3 On-Resistance vs. Drain Current

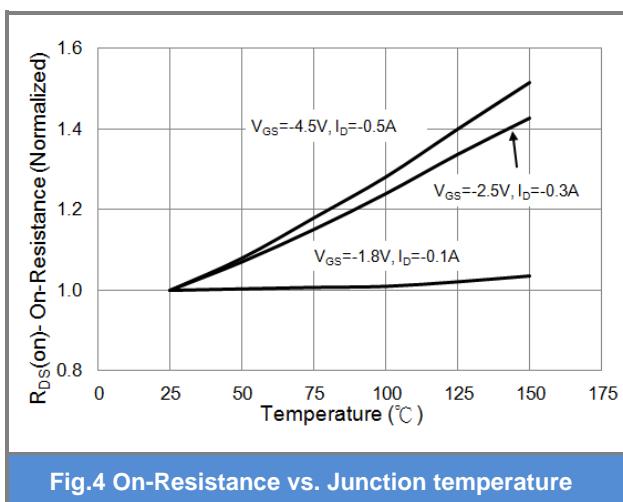


Fig.4 On-Resistance vs. Junction temperature

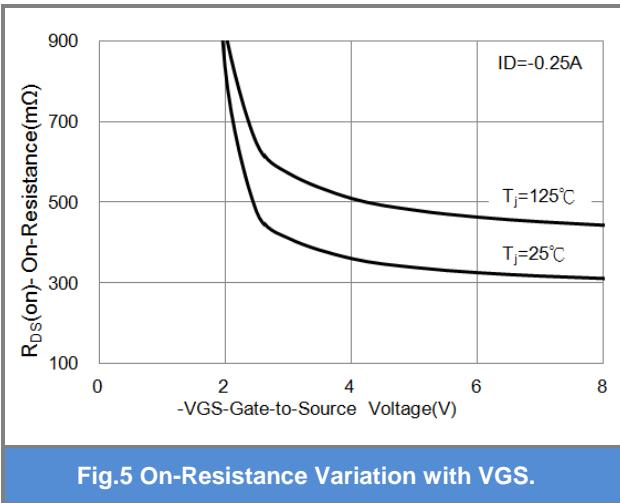


Fig.5 On-Resistance Variation with VGS.

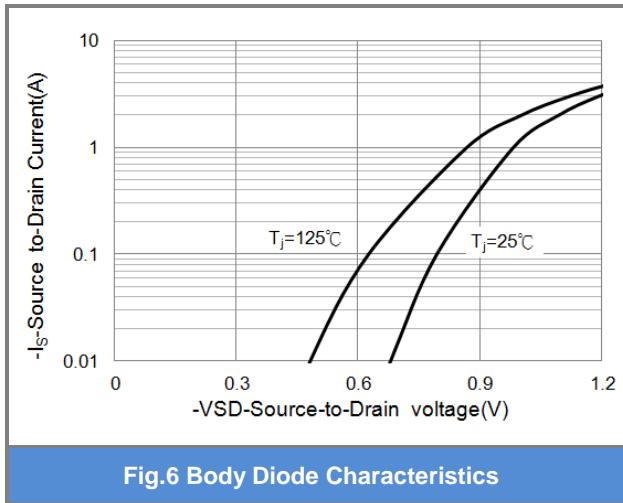
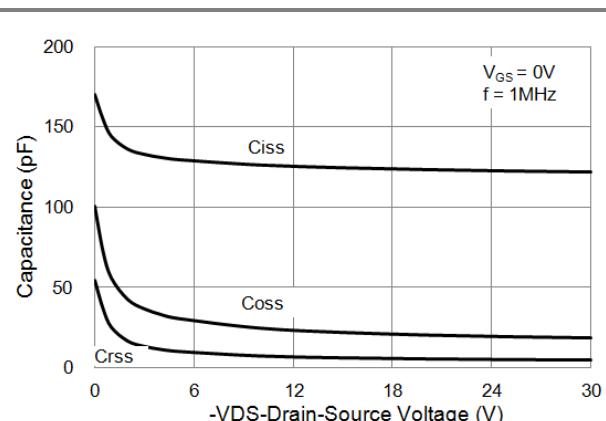
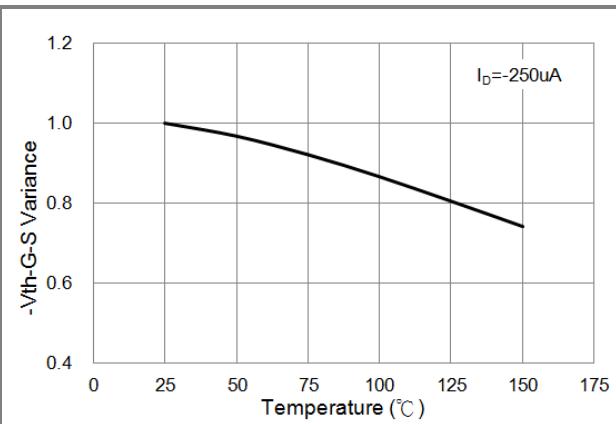
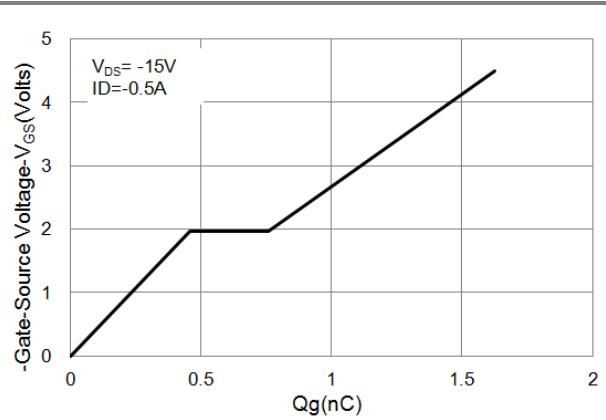


Fig.6 Body Diode Characteristics



## PJE8405

### TYPICAL CHARACTERISTIC CURVES





## PJE8405

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### PART NO. PACKING CODE VERSION

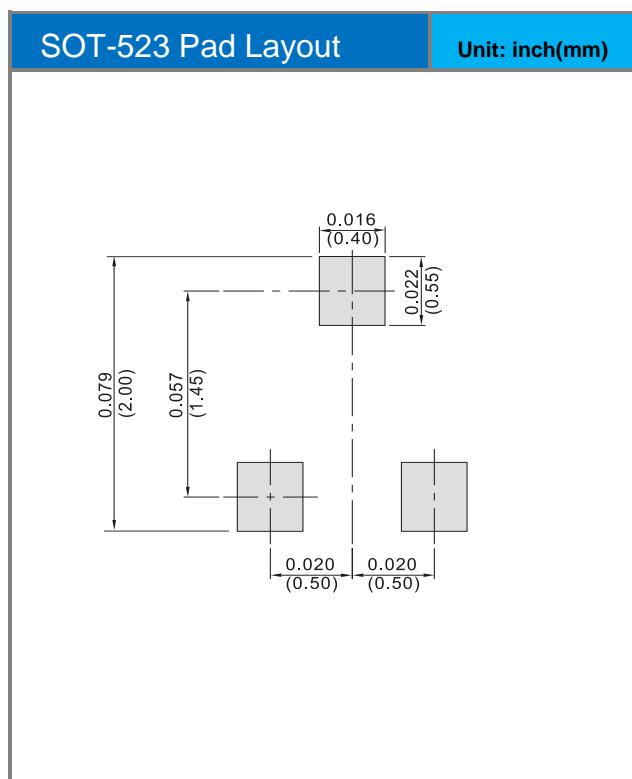
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| Part No. Packing Code | Package Type | Packing Type     | Marking | Version                        |
|-----------------------|--------------|------------------|---------|--------------------------------|
| PJE8405_R1_00001      | SOT-523      | 4K pcs / 7" reel | E05     | Halogen free<br>RoHS compliant |

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### MOUNTING PAD LAYOUT

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## PJE8405

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